

#### **Description**

The AOSP21321 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a

Battery protection or in other Switching application.



SOP-8

#### **General Features**

 $V_{DS} = -30 V I_{D} = -11 A$ 

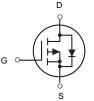
 $R_{DS(ON)}$  < 16m $\Omega$  @  $V_{GS}$ =10V

## **Application**

Battery protection

Load switch

Uninterruptible power supply



P-Channel MOSFET

## **Package Marking and Ordering Information**

Product ID	Pack	Brand	Qty(PCS)
AOSP21321	SOP-8	HXY MOSFET	3000

## Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	- 30	V
VGS	Gate-Source Voltage	±20	V
I <sub>D</sub> @T <sub>A</sub> =25°C	Drain Current <sup>3</sup> , V <sub>GS</sub> @ 10V	-11	А
IDM	Pulsed Drain Current <sup>1</sup>	-40	А
PD@TA=25°C	Total Power Dissipation	3.7	W
TSTG	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	℃
Rthj-a	Maximum Thermal Resistance, Junction-ambient <sup>3</sup>	33.8	°C/W



# Electrical Characteristics (T<sub>J</sub> = 25°C, unless otherwise noted)

Symbol	Parameter	<b>Test Condition</b>	Min.	Тур.	Max.	Units
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> = -250μA	-30	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = -30V, V <sub>GS</sub> =0V,	-	-	-1	μΑ
I <sub>GSS</sub>	Gate to Body Leakage Current	V <sub>DS</sub> =0V, V <sub>GS</sub> = ±20V	-	-	±100	nA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$ , $I_D=-250\mu A$	-1.0	-1.6	-2.5	V
D	Static Drain-Source on-Resistance	V <sub>GS</sub> = -10V, I <sub>D</sub> = -10A		13	16	mΩ
$R_{DS(on)}$		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -5A		18	27	
C <sub>iss</sub>	Input Capacitance	\	-	1330	-	pF
Coss	Output Capacitance	$V_{DS}$ = -15V, $V_{GS}$ =0V, f=1.0MHz	1	183	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	I-1.0IVII12		156	-	pF
Qg	Total Gate Charge	\/ - 45\/   - 54	-	22	-	nC
Qgs	Gate-Source Charge	$V_{DS}$ = -15V, $I_{D}$ = -5A, $V_{GS}$ = -10V	-	1.0	-	nC
Q <sub>gd</sub>	Gate-Drain("Miller") Charge	VGS10V	-	1.8	-	nC
t <sub>d(on)</sub>	Turn-on Delay Time		-	9	-	ns
t <sub>r</sub>	Turn-on Rise Time	$V_{DD}$ = -15V, $I_{D}$ = -10A, $V_{GS}$ =-10V, $R_{GEN}$ =2.5 $\Omega$		13	-	ns
t <sub>d(off)</sub>	Turn-off Delay Time		-	48	-	ns
t <sub>f</sub>	Turn-off Fall Time		-	20	-	ns
Is	Maximum Continuous Drain to Source Diode Forward		-	-	-11	Α
I <sub>SM</sub>	Current  Maximum Pulsed Drain to Source Diode Forward Current		-	_	-40	Α
ISM	Drain to Source Diode Forward	Joue Forward Current		-	-40	A
$V_{\text{SD}}$	Voltage	$V_{GS}$ =0 $V$ , $I_{S}$ = -15 $A$	ı	-0.8	-1.2	V
trr	Reverse Recovery Time	TJ=25℃,	-	64	-	ns
Qrr	Reverse Recovery Charge	$V_{DD}$ = -24V,I <sub>F</sub> =-2.8A, dI/dt=-100A/ $\mu$ s	-	25	-	nC

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

- 2. EAS condition:  $T_J = 25\,^{\circ}\!\!\mathrm{C}$  ,  $V_{GS} = 10V$  ,  $R_G = 25\Omega$  , L=0.5mH,  $I_{AS} = -12.7A$
- 3. Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%



# **Typical Characteristics**

Figure1: Output Characteristics

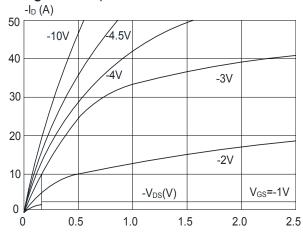


Figure 2: Typical Transfer Characteristics

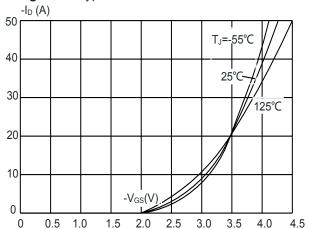


Figure 3:On-resistance vs. Drain Current

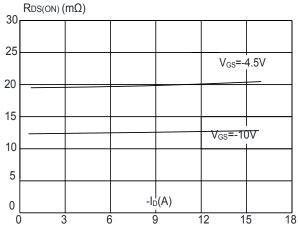


Figure 4: Body Diode Characteristics

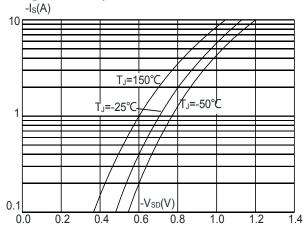


Figure 5: Gate Charge Characteristics

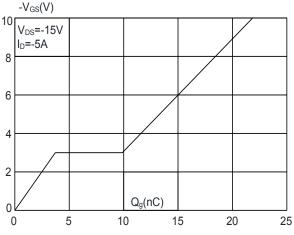
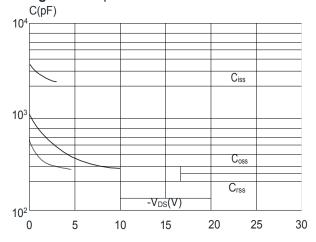
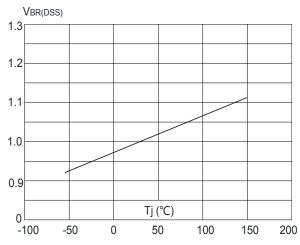


Figure 6: Capacitance Characteristics

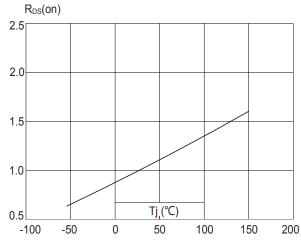




**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



**Figure 8:** Normalized on Resistance vs. Junction Temperature



**Figure 9:** Maximum Safe Operating Area  $-I_D(A)$ 

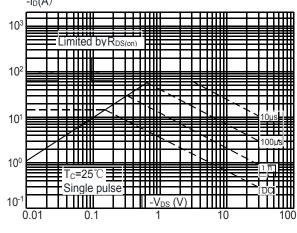
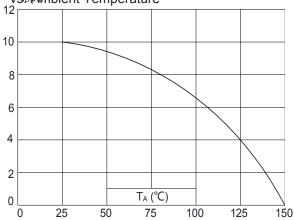
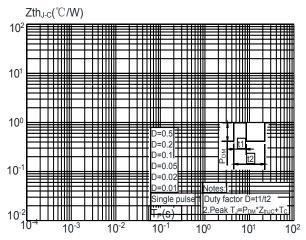


Figure 10: Maximum Continuous Drain Current vsp Ambient Temperature



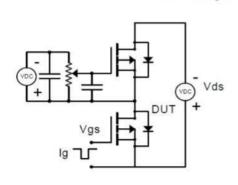
**Figure.11:** Maximum Effective Transient Thermal Impedance, Junction-to-Case

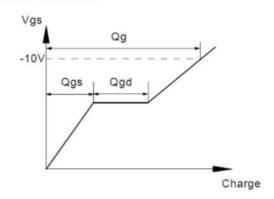




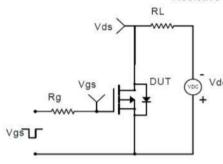
# **Test Circuit**

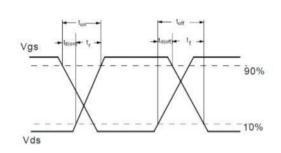
## Gate Charge Test Circuit & Waveform



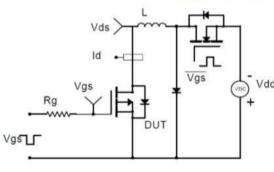


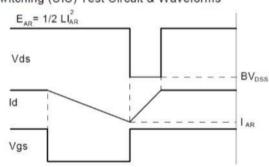
#### Resistive Switching Test Circuit & Waveforms



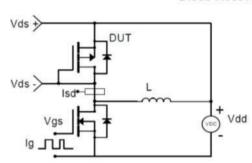


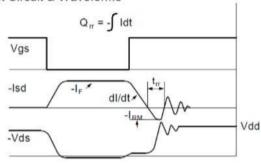
## Unclamped Inductive Switching (UIS) Test Circuit & Waveforms





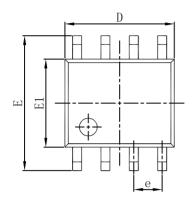
## Diode Recovery Test Circuit & Waveforms

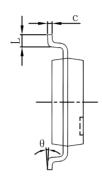


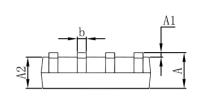




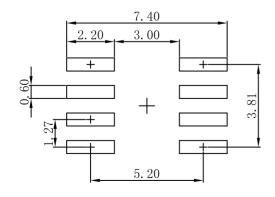
# **SOP-8 Package Outline Dimensions**







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
A	1. 350	1.750	0.053	0.069	
A1	0.100	0. 250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0. 013	0.020	
c	0.170	0.250	0.007	0.010	
D	4.800	5.000	0.189	0. 197	
e	1.270 (BSC)		0.050 (BSC)		
E	5.800	6. 200	0. 228	0. 244	
E1	3.800	4.000	0.150	0. 157	
L	0.400	1. 270	0.016	0.050	
θ	0°	8°	0°	8°	



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
  3.The pad layout is for reference purposes only.



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